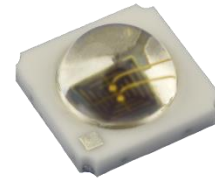


940nm Dual Junction Infrared LED Emitter

LZ1-00R702



Key Features

- 940nm Dual Junction Infrared LED
- Ultra-small foot print – 4.4mm x 4.4mm
- Surface mount ceramic package with integrated glass lens
- Very low Thermal Resistance (6.0°C/W)
- Very high Radiant Flux density
- JEDEC Level 1 for Moisture Sensitivity Level
- Lead (Pb) free and RoHS compliant
- Reflow solderable
- Emitter available on Standard or Miniature MCPCB (optional)

Typical Applications

- Surveillance cameras
- Traffic management
- Gesture recognition
- Machine vision
- Biometric sensing

Description

The LZ1-00R702 940nm Dual Junction Infrared LED emitter generates 1150mW nominal output at 3.2W power dissipation in an extremely small package. With a 4.4mm x 4.4mm ultra-small footprint, this package provides exceptional radiant flux density. The patent-pending design has unparalleled thermal and optical performance. The high quality materials used in the package are chosen to optimize optical performance and minimize stresses which results in monumental reliability and flux maintenance. The robust product design thrives in outdoor applications with high ambient temperatures and high humidity.

Notes

This product emits non visible infrared light, which can be hazardous depending on total system configuration (including, but not limited to optics, drive current and temperature). Observe safety precaution given in IEC 62471 when operating this product.

Part number options

Base part number

Part number	Description
LZ1-00R702	LZ1 Infrared 940nm Dual Junction Emitter
LZ1-10R702	LZ1 Infrared 940nm Dual Junction Emitter on Standard Star MCPCB
LZ1-30R702	LZ1 Infrared 940nm Dual Junction Emitter on Miniature Round MCPCB

Bin kit option codes

R7, Infrared Dual Junction (940nm)			
Kit number suffix	Min flux Bin	Wavelength Bin Range	Description
0000	L44M	F09	full distribution flux; full distribution wavelength

Notes:

1. Default bin kit option is -0000

Radiant Flux Bins

Table 1:

Bin Code	Minimum Radiant Flux (Φ) @ $I_F = 1000\text{mA}$ ^[1,2] (mW)	Maximum Radiant Flux (Φ) @ $I_F = 1000\text{mA}$ ^[1,2] (mW)
L44M	950	1250

Notes for Table 1:

1. Radiant flux performance is measured at 10ms pulse, $T_C = 25^\circ\text{C}$. LED Engin maintains a tolerance of $\pm 10\%$ on flux measurements.
2. Future products will have even higher levels of radiant flux performance. Contact LED Engin Sales for updated information.

Peak Wavelength Bin

Table 2:

Bin Code	Minimum Peak Wavelength (λ_p) @ $I_F = 1000\text{mA}$ ^[1] (nm)	Maximum Peak Wavelength (λ_p) @ $I_F = 1000\text{mA}$ ^[1] (nm)
F09	920	960

Notes for Table 3:

1. Peak wavelength is measured at 10ms pulse, $T_C = 25^\circ\text{C}$. LED Engin maintains a tolerance of $\pm 2.0\text{nm}$ on peak wavelength measurements.

Forward Voltage Bin

Table 3:

Bin Code	Minimum Forward Voltage (V_F) @ $I_F = 1000\text{mA}$ ^[1] (V)	Maximum Forward Voltage (V_F) @ $I_F = 1000\text{mA}$ ^[1] (V)
0	2.7	3.7

Notes for Table 3:

1. Forward voltage is measured at 10ms pulse, $T_C = 25^\circ\text{C}$. LED Engin maintains a tolerance of $\pm 0.04\text{V}$ for forward voltage measurements.

Absolute Maximum Ratings

Table 4:

Parameter	Symbol	Value	Unit
DC Forward Current at $T_{J(MAX)}=120^{\circ}C$ ^[1]	I_F	1200	mA
DC Forward Current at $T_{J(MAX)}=145^{\circ}C$ ^[1]	I_F	1000	mA
Peak Pulsed Forward Current ^[2]	I_{FP}	5000	mA
Reverse Voltage	V_R	See Note 3	V
Storage Temperature	T_{stg}	-40 ~ +125	$^{\circ}C$
Junction Temperature	$T_{J(MAX)}$	145	$^{\circ}C$
Soldering Temperature ^[4]	T_{sol}	260	$^{\circ}C$

Notes for Table 4:

- Maximum DC forward current is determined by the overall thermal resistance and ambient temperature. Follow the curves in Figure 11 for current derating.
- Pulse forward current conditions: Pulse Width $\leq 150\mu s$ and Duty Cycle $\leq 10\%$.
- LEDs are not designed to be reverse biased.
- Solder conditions per JEDEC 020D. See Reflow Soldering Profile Figure 3.
- LED Engin recommends taking reasonable precautions towards possible ESD damages and handling the LZ1-00R702 in an electrostatic protected area (EPA). An EPA may be adequately protected by ESD controls as outlined in ANSI/ESD S6.1.

Optical Characteristics @ $T_C = 25^{\circ}C$

Table 5:

Parameter	Symbol	Typical	Unit
Radiant Flux (@ $I_F = 1000mA$) ^[1]	Φ	1150	mW
Radiant Flux (@ $I_F = 1200mA$) ^[1]	Φ	1375	mW
Wall Plug Efficiency (@ $I_F = 1000mA$)	η	38	%
Peak Wavelength	λ_p	940	nm
Viewing Angle ^[2]	$2\Theta_{1/2}$	90	Degrees
Total Included Angle ^[3]	$\Theta_{0.9V}$	110	Degrees

Notes for Table 5:

- This product emits non visible infrared light, which can be hazardous depending on total system configuration (including, but not limited to optics, drive current and temperature). Observe safety precaution given in IEC 62471 when operating this product.
- Viewing Angle is the off axis angle from emitter centerline where the radiant power is 1/2 of the peak value.
- Total Included Angle is the total angle that includes 90% of the total radiant flux.

Electrical Characteristics @ $T_C = 25^{\circ}C$

Table 6:

Parameter	Symbol	Typical	Unit
Forward Voltage (@ $I_F = 1000mA$)	V_F	3.00	V
Forward Voltage (@ $I_F = 1200mA$)	V_F	3.05	V
Temperature Coefficient of Forward Voltage	$\Delta V_F / \Delta T_J$	-2.0	mV/ $^{\circ}C$
Thermal Resistance (Junction to Case)	$R\Theta_{J-C}$	6.0	$^{\circ}C/W$

Peak Pulse Forward Current (I_{FP}) Capability

Table 7:

Parameter	Value	Unit
$t_p = 150\mu s$, $D=10\%$	5000	mA
$t_p = 10ms$, $D=20\%$	2000	mA

Notes:

- t_p = Pulse Width, T = Period, D = Duty Cycle = t_p/T .

IPC/JEDEC Moisture Sensitivity Level

Table 8 - IPC/JEDEC J-STD-20 MSL Classification:

Level	Floor Life		Soak Requirements			
	Time	Conditions	Standard	Accelerated	Time (hrs)	Conditions
1	1 Year	$\leq 30^\circ C$ / 60% RH	168 +5/-0	85°C/ 60% RH	n/a	n/a

Notes for Table 8:

- The standard soak time is the sum of the default value of 24 hours for the semiconductor manufacturer's exposure time (MET) between bake and bag and the floor life of maximum time allowed out of the bag at the end user of distributor's facility.

Mechanical Dimensions (mm)

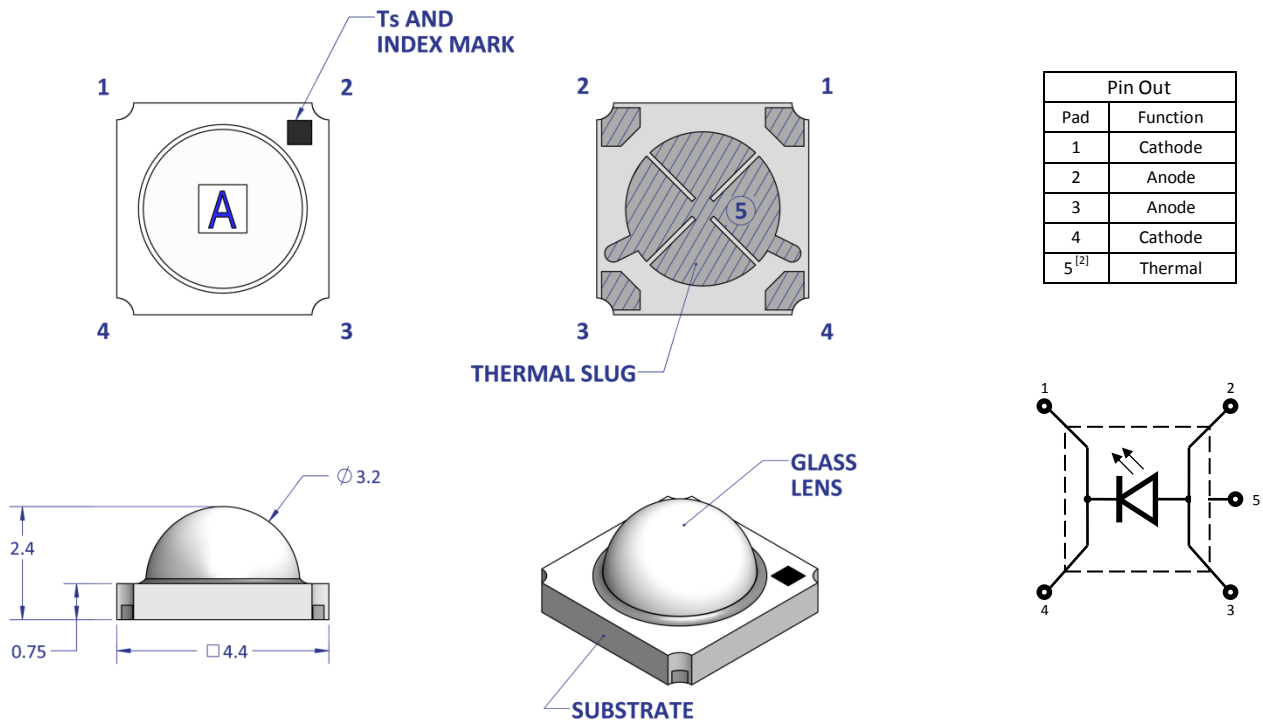


Figure 1: Package outline drawing

Notes for Figure 1:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.
2. Thermal contact, Pad 5, is electrically neutral.

Recommended Solder Pad Layout (mm)

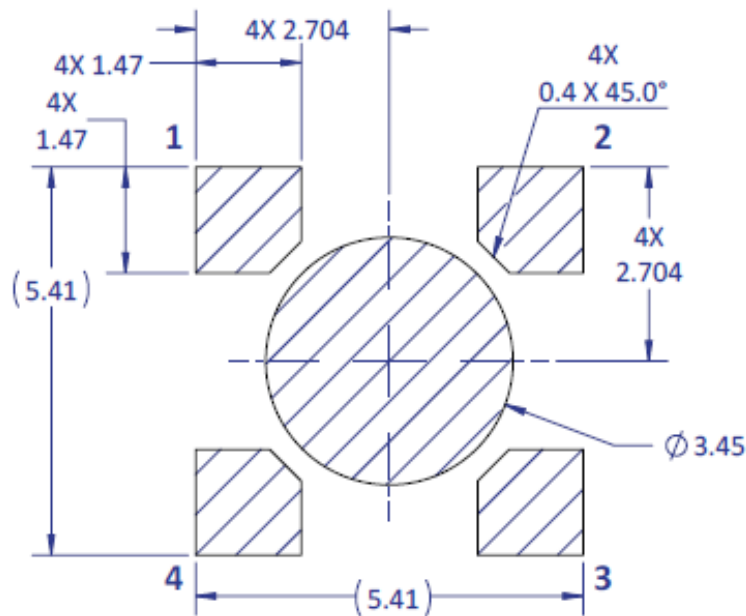


Figure 2a: Recommended solder pad layout for anode, cathode, and thermal pad

Note for Figure 2a:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.

Recommended Solder Mask Opening (mm)

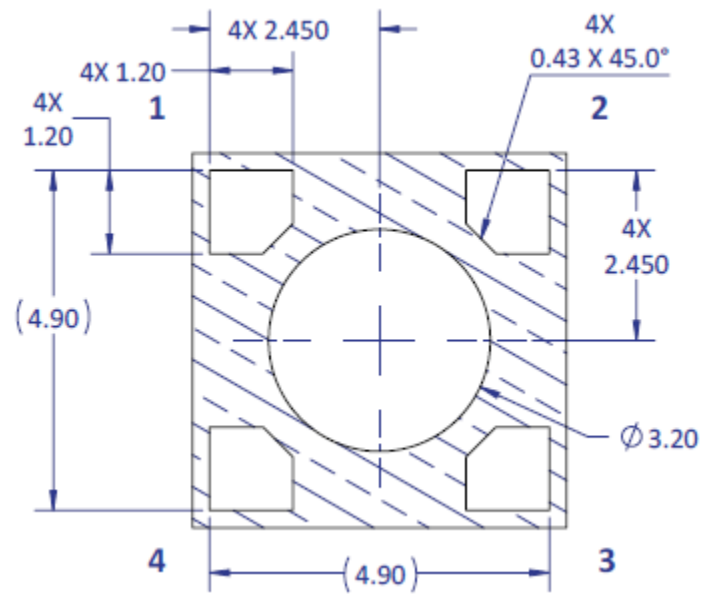


Figure 2b: Recommended solder mask opening for anode, cathode, and thermal pad

Note for Figure 2b:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.

Recommended Apertures for 8mil Stencil (mm)

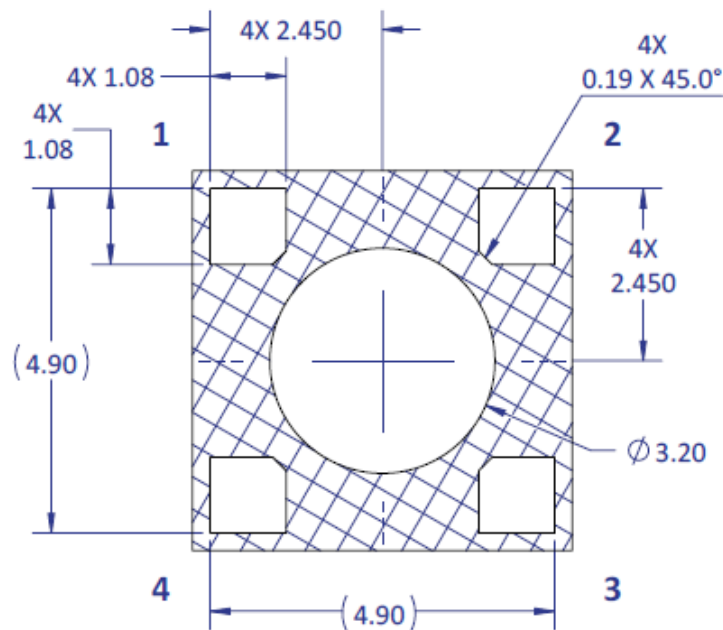


Figure 2c: Recommended solder mask opening for anode, cathode, and thermal pad

Note for Figure 2c:

1. Unless otherwise noted, the tolerance = ± 0.20 mm.

Reflow Soldering Profile

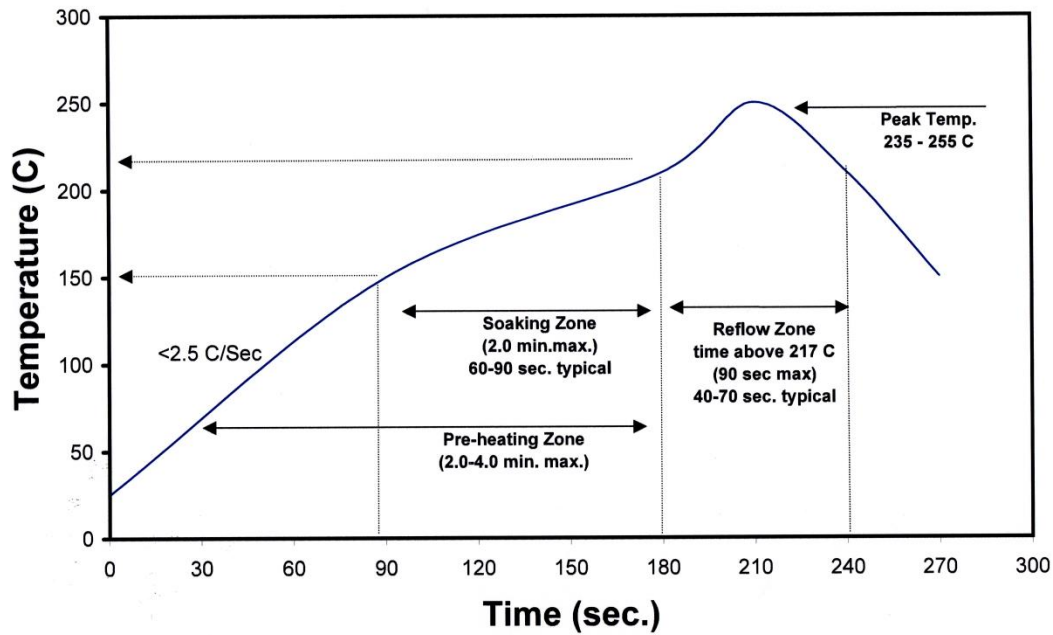


Figure 3: Reflow soldering profile for lead free soldering.

Typical Radiation Pattern

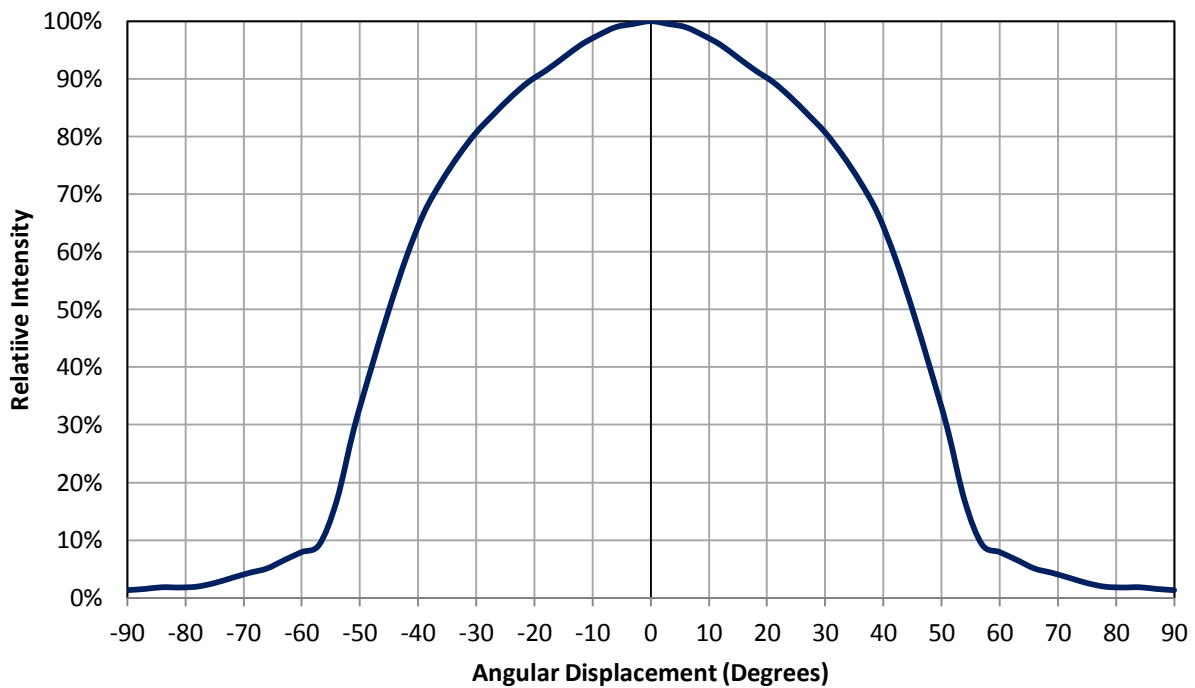


Figure 4: Typical representative spatial radiation pattern.

Typical Relative Spectral Power Distribution

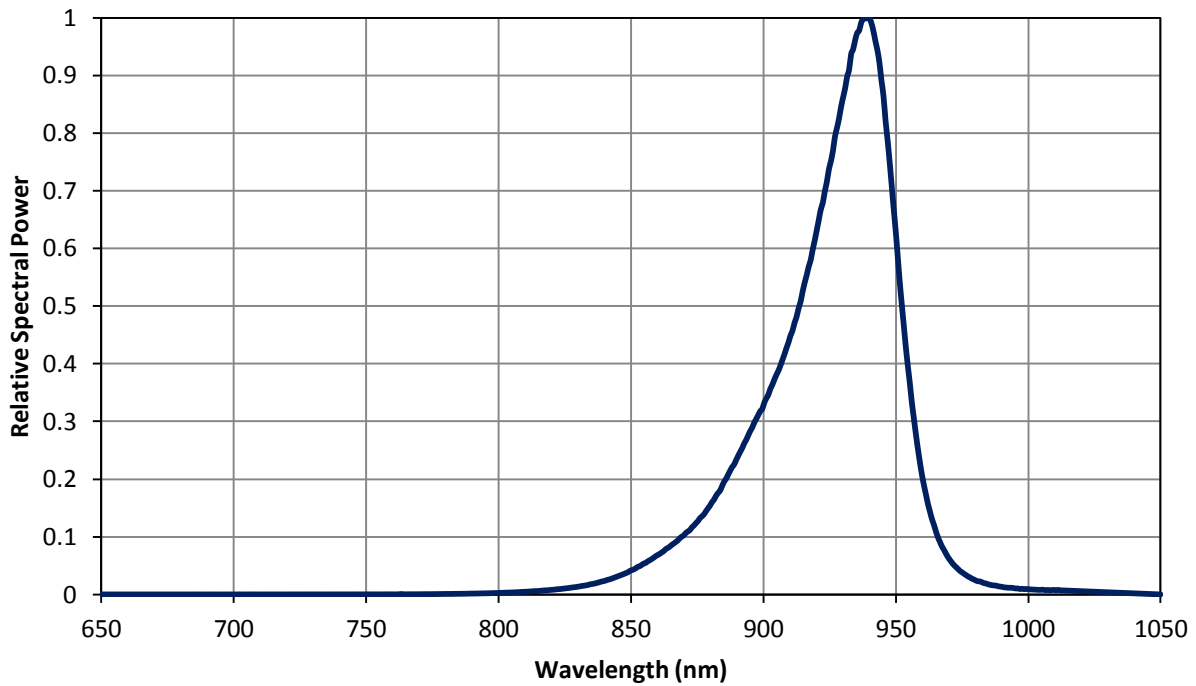


Figure 5: Relative spectral power vs. wavelength @ $T_c = 25^\circ\text{C}$.

Typical Forward Current Characteristics

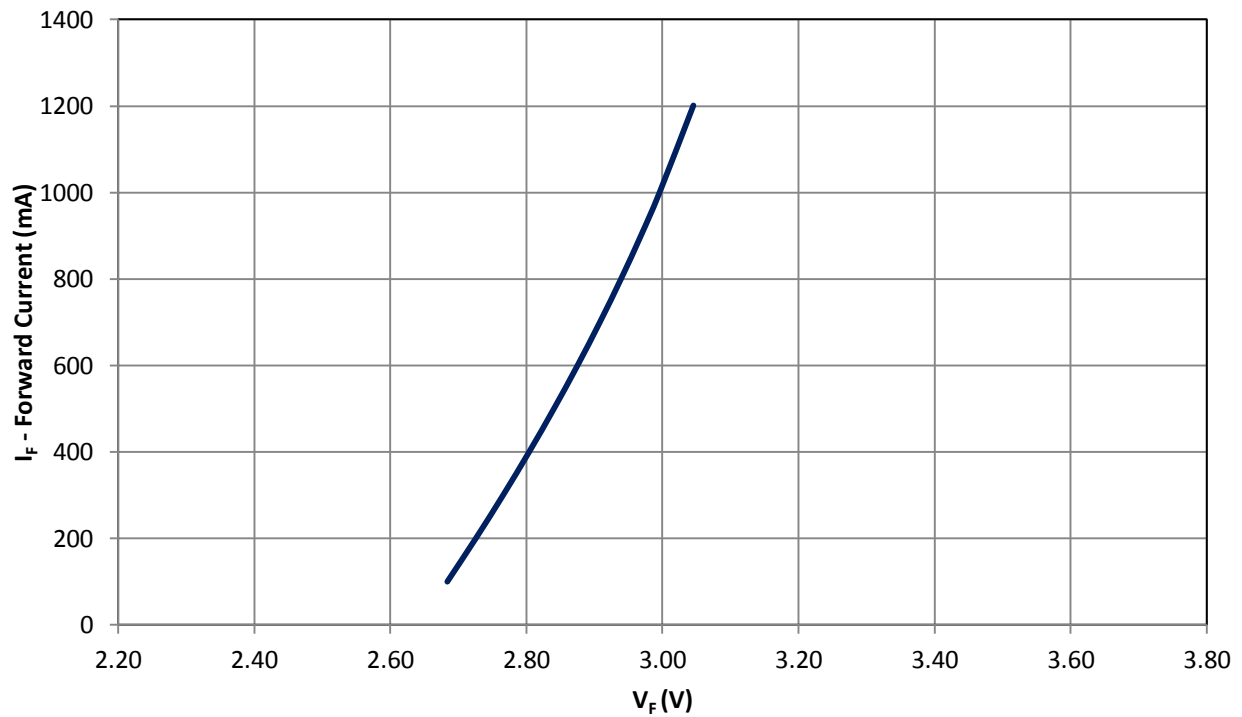


Figure 6: Typical forward current vs. forward voltage @ $T_c = 25^\circ\text{C}$

Typical Normalized Radiant Flux over Current

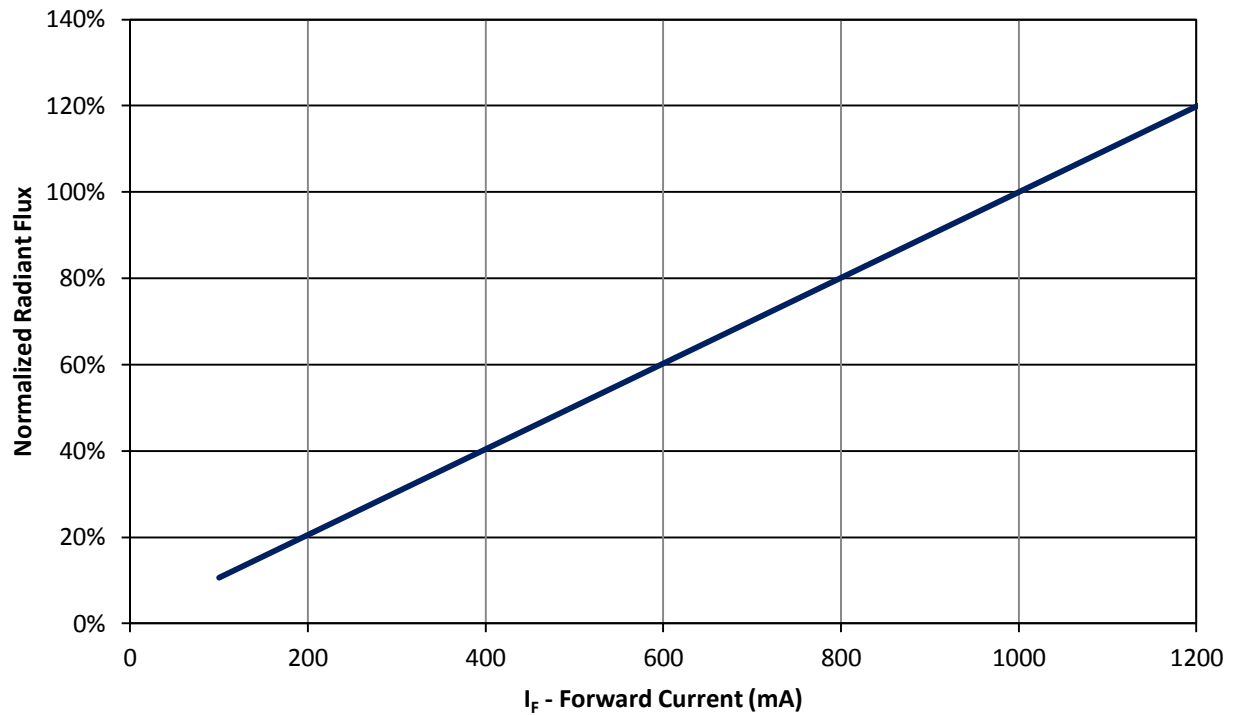


Figure 7: Typical normalized radiant flux vs. forward current @ $T_C = 25^\circ\text{C}$.

Typical Normalized Radiant Flux over Case Temperature

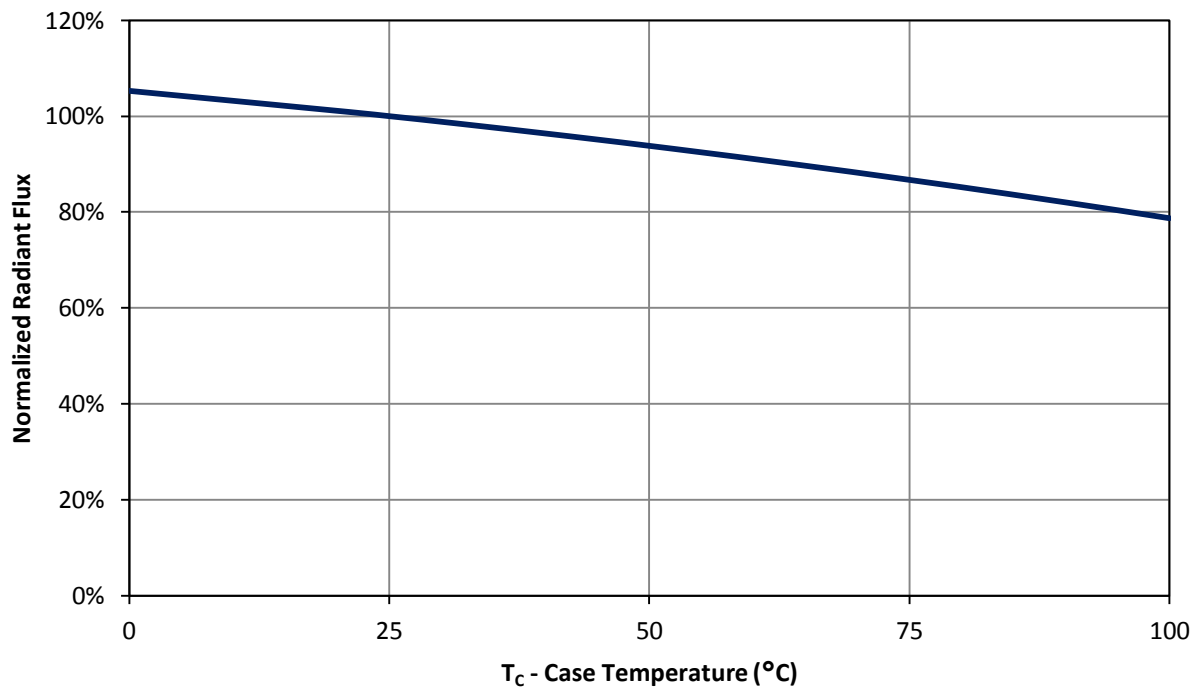


Figure 8: Typical normalized radiant flux vs. case temperature.

Typical Peak Wavelength Shift over Current

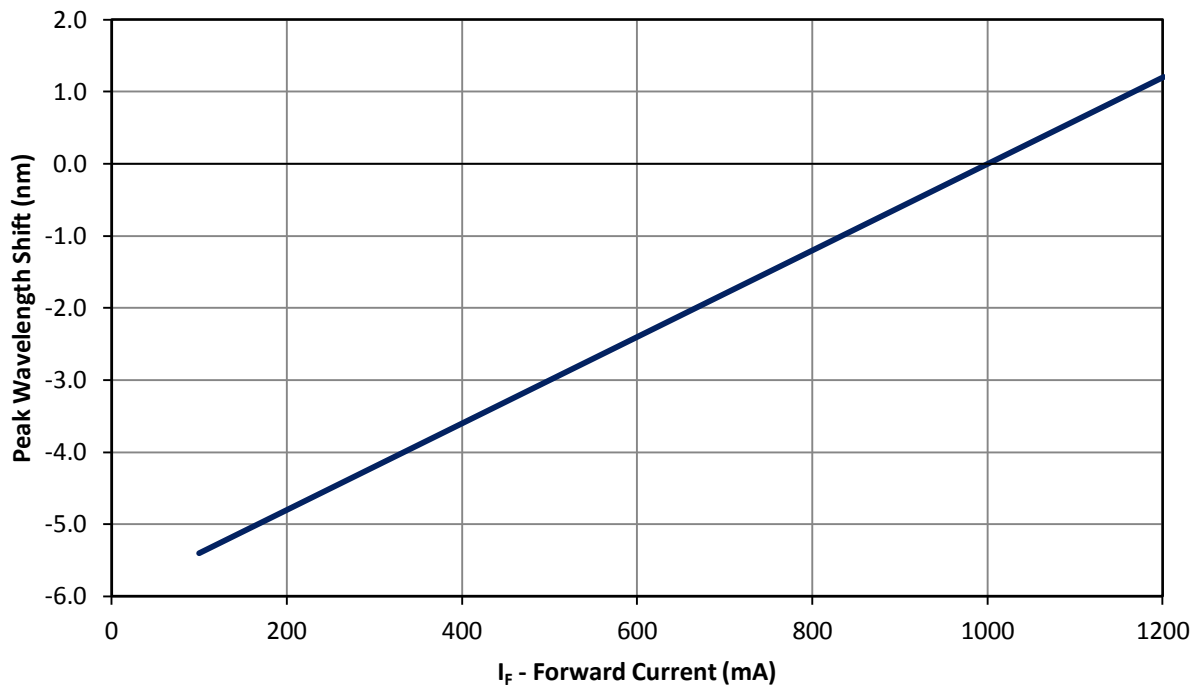


Figure 9: Typical peak wavelength shift vs. forward current @ $T_c = 25^\circ\text{C}$

Typical Peak Wavelength Shift over Case Temperature

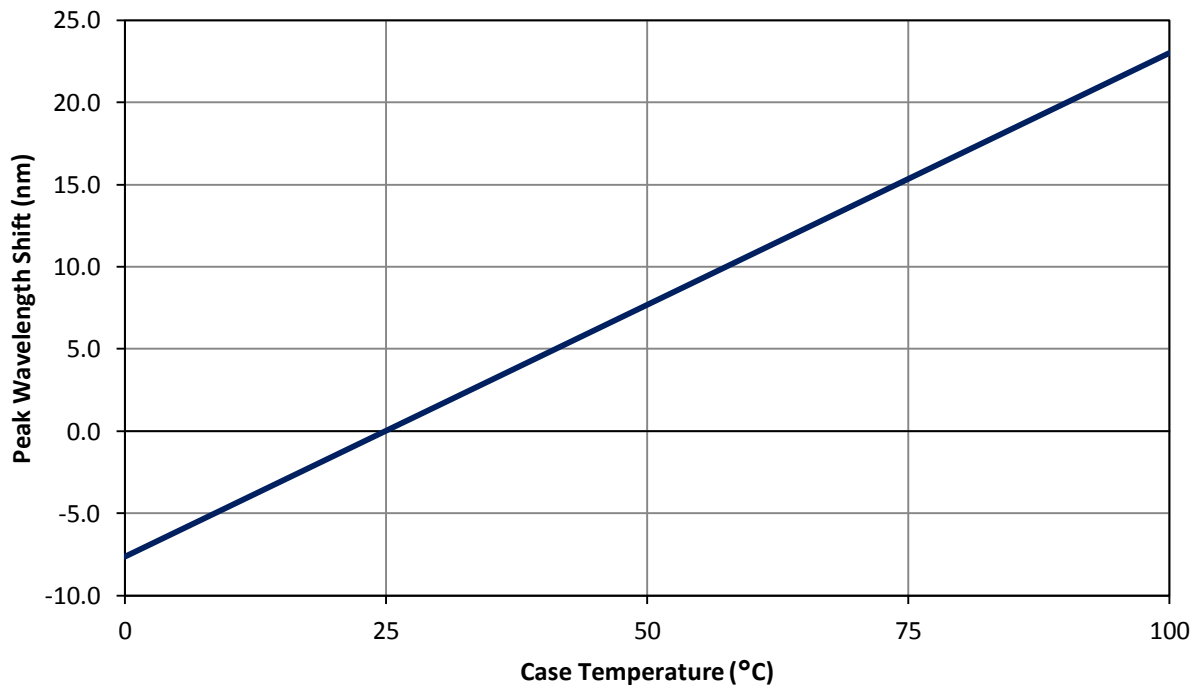


Figure 10: Typical peak wavelength shift vs. case temperature.

Current De-rating

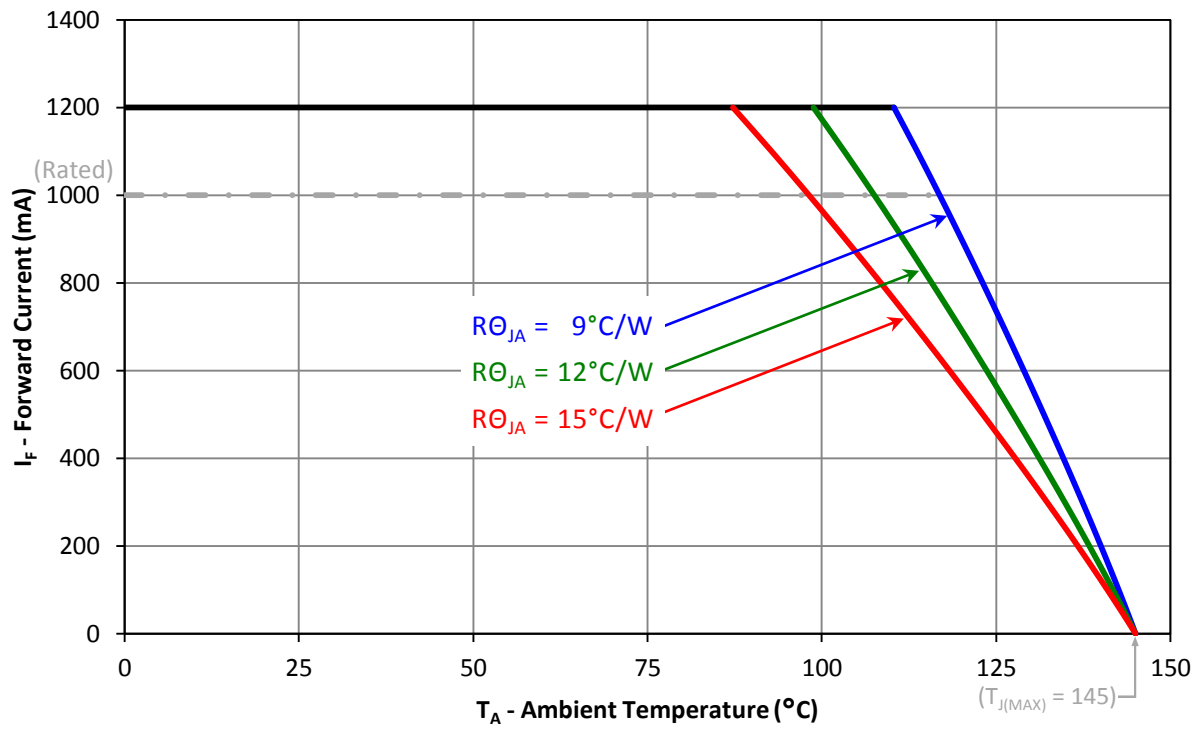


Figure 11: Maximum forward current vs. ambient temperature based on $T_{J(MAX)} = 145^\circ\text{C}$.

Notes for Figure 11:

1. $R\theta_{JC}$ [Junction to Case Thermal Resistance] for the LZ1-00R702 is typically 6.0°C/W .
2. $R\theta_{JA}$ [Junction to Ambient Thermal Resistance] = $R\theta_{JC} + R\theta_{CA}$ [Case to Ambient Thermal Resistance].

Emitter Tape and Reel Specifications (mm)

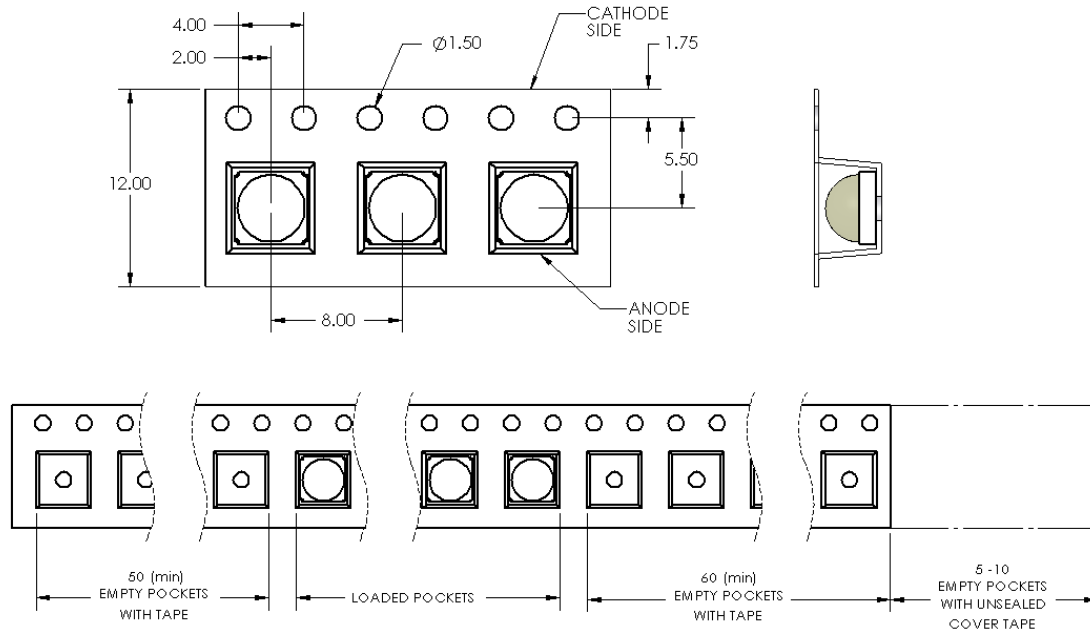


Figure 12: Emitter carrier tape specifications (mm).

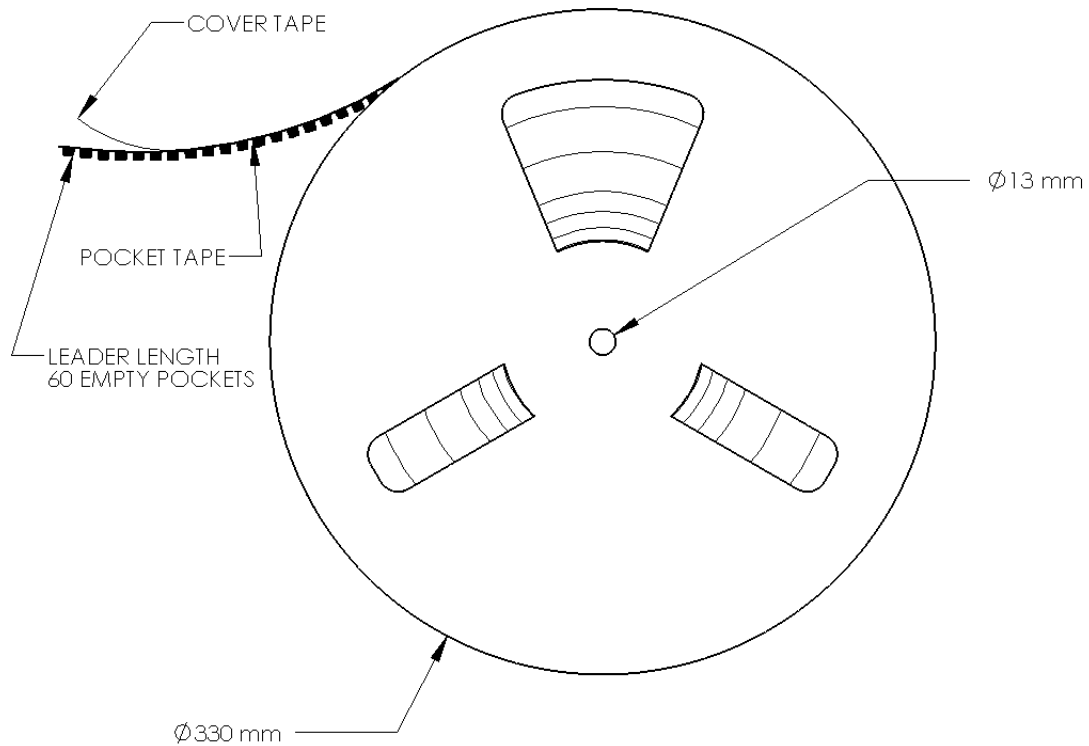


Figure 13: Emitter reel specifications (mm).

Notes for Figure 13:

1. Reel quantity minimum: 200 emitters. Reel quantity maximum: 2500 emitters.

LZ1 MCPCB Family

Part number	Type of MCPCB	Diameter (mm)	Emitter + MCPCB Thermal Resistance (°C/W)	Typical V _F (V)	Typical I _F (mA)
LZ1-1xxxxx	1-channel Star	19.9	6.0 + 1.5 = 7.5	3.0	1000
LZ1-3xxxxx	1-channel Mini	11.5	6.0 + 2.0 = 8.0	3.0	1000

Mechanical Mounting of MCPCB

- MCPCB bending should be avoided as it will cause mechanical stress on the emitter, which could lead to substrate cracking and subsequently LED dies cracking.
- To avoid MCPCB bending:
 - Special attention needs to be paid to the flatness of the heat sink surface and the torque on the screws.
 - Care must be taken when securing the board to the heat sink. This can be done by tightening three M3 screws (or #4-40) in steps and not all the way through at once. Using fewer than three screws will increase the likelihood of board bending.
 - It is recommended to always use plastics washers in combinations with the three screws.
 - If non-taped holes are used with self-tapping screws, it is advised to back out the screws slightly after tightening (with controlled torque) and then re-tighten the screws again.

Thermal interface material

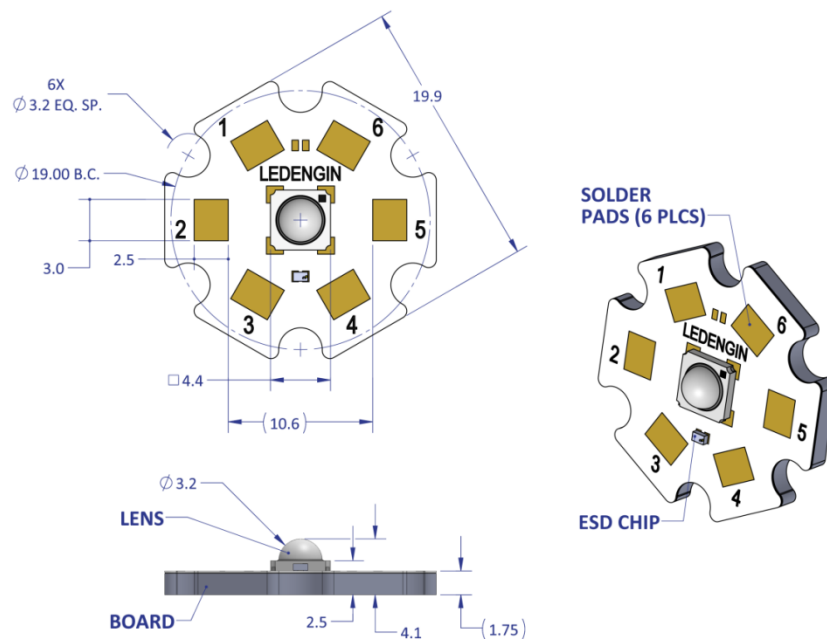
- To properly transfer heat from LED emitter to heat sink, a thermally conductive material is required when mounting the MCPCB on to the heat sink.
- There are several varieties of such material: thermal paste, thermal pads, phase change materials and thermal epoxies. An example of such material is Electrolube EHTC.
- It is critical to verify the material's thermal resistance to be sufficient for the selected emitter and its operating conditions.

Wire soldering

- To ease soldering wire to MCPCB process, it is advised to preheat the MCPCB on a hot plate of 125-150°C. Subsequently, apply the solder and additional heat from the solder iron will initiate a good solder reflow. It is recommended to use a solder iron of more than 60W.
- It is advised to use lead-free, no-clean solder. For example: SN-96.5 AG-3.0 CU 0.5 #58/275 from Kester (pn: 24-7068-7601)

LZ1-1xxxxx

1 channel, Standard Star MCPCB (1x1) Dimensions (mm)



Notes:

- Unless otherwise noted, the tolerance = ± 0.2 mm.
- Slots in MCPCB are for M3 or #4-40 mounting screws.
- LED Engin recommends plastic washers to electrically insulate screws from solder pads and electrical traces.
- LED Engin recommends using thermal interface material when attaching the MCPCB to a heat sink.
- The thermal resistance of the MCPCB is: $R_{\theta C-B} 1.5^{\circ}\text{C/W}$

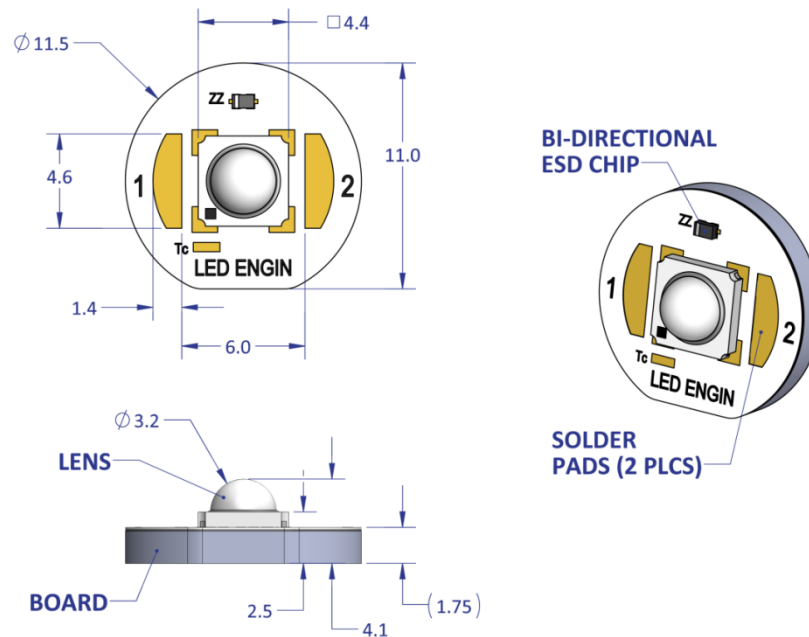
Components used

MCPCB:	HT04503	(Bergquist)
ESD/TVS Diode:	BZT52C5V1LP-7	(Diodes, Inc., for 1 LED die)
	VBUS05L1-DD1	(Vishay Semiconductors, for 1 LED die)

Pad layout			
Ch.	MCPCB Pad	String/die	Function
1	1,2,3	1/A	Cathode -
	4,5,6		Anode +

LZ1-3xxxxx

1 channel, Mini Round MCPCB (1x1) Dimensions (mm)



Notes:

- Unless otherwise noted, the tolerance = ± 0.20 mm.
- LED Engin recommends using thermal interface material when attaching the MCPCB to a heat sink.
- The thermal resistance of the MCPCB is: $R_{\theta C-B} 2.0^{\circ}\text{C/W}$

Components used

MCPCB:	HT04503	(Bergquist)
ESD/TVS Diode:	BZT52C5V1LP-7	(Diodes, Inc., for 1 LED die)
	VBUS05L1-DD1	(Vishay Semiconductors, for 1 LED die)

Pad layout			
Ch.	MCPCB Pad	String/die	Function
1	1	1/A	Anode +
	2		Cathode -

Company Information

LED Engin, Inc., based in California's Silicon Valley, specializes in ultra-bright, ultra compact solid state lighting solutions allowing lighting designers & engineers the freedom to create uncompromised yet energy efficient lighting experiences. The LuxiGen™ Platform — an emitter and lens combination or integrated module solution, delivers superior flexibility in light output, ranging from 3W to 90W, a wide spectrum of available colors, including whites, multi-color and UV, and the ability to deliver upwards of 5,000 high quality lumens to a target. The small size combined with powerful output allows for a previously unobtainable freedom of design wherever high-flux density, directional light is required. LED Engin's packaging technologies lead the industry with products that feature lowest thermal resistance, highest flux density and consummate reliability, enabling compact and efficient solid state lighting solutions.

LED Engin is committed to providing products that conserve natural resources and reduce greenhouse emissions.

LED Engin reserves the right to make changes to improve performance without notice.

Please contact sales@ledengin.com or (408) 922-7200 for more information.